2SA949-Y(TE6,F,M)

2SA949-Y(TE6,F,M) Information

For Reference Only

Part Number 2SA949-Y(TE6,F,M)
Manufacturer Toshiba Semiconductor and Storage
Category Discrete Semiconductor Products
Transistors - Bipolar (BJT) - Single
Description TRANS PNP 50MA 150V TO226-3
Package TO-226-3, TO-92-3 Long Body

For the pricing/inventory/lead time, please contact us
Website: https://www.heisener.com
E-mail: salesdept@heisener.com

Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.

2SA949-Y(TE6,F,M) Specifications

Manufacturer Part Number	2SA949-Y(TE6,F,M)
Manufacturer	Toshiba Semiconductor and Storage
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - Single
Package	TO-226-3, TO-92-3 Long Body
Series	-
Transistor Type	PNP
Current - Collector (Ic) (Max)	50mA
Voltage - Collector Emitter Breakdown (Max)	150V
Vce Saturation (Max) @ Ib, Ic	800mV @ 1mA, 10A
Current - Collector Cutoff (Max)	100nA (ICBO)
DC Current Gain (hFE) (Min) @ Ic, Vce	70 @ 10mA, 5V
Power - Max	800mW
Frequency - Transition	120MHz
Operating Temperature	150°C (TJ)
Mounting Type	Through Hole
Package / Case	TO-226-3, TO-92-3 Long Body
Supplier Device Package	TO-92MOD
	Report errors?

2SA949-Y(TE6,F,M) Guarantees

Quality Guarantees
We provide 90 days warranty. *
If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

Service Guarantees
We guarantee 100% customer satisfaction.
Our experienced sales team and tech support team back our services to satisfy all our customers.

2SA949-Y(TE6,F,M) Payment Methods

2SA949-Y(TE6,F,M) Shipping Methods

If you have any question about 2SA949-Y(TE6,F,M), please do not hesitate to contact us!
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